NEC

NPN SILICON EPITAXIAL TWIN TRANSISTOR | UPA836TF

FEATURES

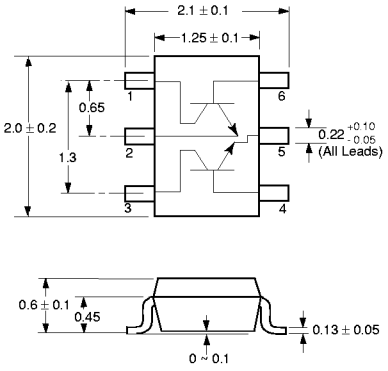
- **LOW NOISE:**
  Q1:NF = 1.5 dB TYP at f = 2 GHz, V_{CE} = 3 V, Ic = 3 mA
  Q2:NF = 1.7 dB TYP at f = 2 GHz, V_{CE} = 1 V, Ic = 3 mA
- **HIGH GAIN:**
  Q1: $|S_{21E}|^2$ = 8.5 dB TYP at f = 2 GHz, V_{CE} = 3 V, Ic = 10 mA
  Q2: $|S_{21E}|^2$ = 3.5 dB TYP at f = 2 GHz, V_{CE} = 1 V, Ic = 3 mA
- **6-PIN THIN-TYPE SMALL MINI MOLD PACKAGE**
- **2 DIFFERENT BUILT-IN TRANSISTORS (Q1: NE685, Q2: NE688)**

DESCRIPTION

The UPA836TF has two different built-in transistors for low cost amplifier and oscillator applications up to L and S band. Low noise figures, high gain, high current capability, and medium output give this device high dynamic range and excellent linearity for two-stage amplifiers. This device is also ideally suited for use in a VCO/buffer amplifier application. The thinner package style allows for higher density designs.

OUTLINE DIMENSIONS (Units in mm)

Package Outline TS06 (Top View)



PIN CONNECTIONS
1. Collector (Q1)
2. Emitter (Q1)
3. Collector (Q2)
4. Base (Q2)
5. Emitter (Q2)
6. Base (Q1)

Note:
Pin 1 is the lower left most pin as the package lettering is oriented and read left to right.

ELECTRICAL CHARACTERISTICS (T_A = 25°C)

	PART NUMBER PACKAGE OUTLINE			UPA836TF TS06		
	SYMBOLS	PARAMETERS AND CONDITIONS	UNITS	MIN	TYP	MAX
Q1	I_{CBO}	Collector Cutoff Current at V_{CB} = 5 V, I_E = 0	µA			0.1
	I_{EBO}	Emitter Cutoff Current at V_{EB} = 1 V, I_C = 0	µA			0.1
	h_{FE}	DC Current Gain[1] at V_{CE} = 3 V, I_C = 10 mA		75		150
	f_T	Gain Bandwidth at V_{CE} = 3 V, I_C = 10 mA, f = 2 GHz	GHz		12	
	Cre	Feedback Capacitance[2] at V_{CB} = 3 V, I_E = 0, f = 1 MHz	pF		0.4	0.7
	$\|S_{21E}\|^2$	Insertion Power Gain at V_{CE} = 3 V, I_C =10 mA, f = 2 GHz	dB	7	8.5	
	NF	Noise Figure at V_{CE} = 3 V, I_C = 3 mA, f = 2 GHz	dB		1.5	2.5
Q2	I_{CBO}	Collector Cutoff Current at V_{CB} = 5 V, I_E = 0	µA			0.1
	I_{EBO}	Emitter Cutoff Current at V_{EB} = 1 V, I_C = 0	µA			0.1
	h_{FE}	DC Current Gain[1] at V_{CE} = 1 V, I_C = 3 mA		100		145
	f_T	Gain Bandwidth (1) at V_{CE} = 1 V, I_C = 3 mA, f = 2 GHz	GHz	4.0	4.5	
	f_T	Gain Bandwidth (2) at V_{CE} = 3 V, I_C = 20 mA, f = 2 GHz	GHz		9.0	
	Cre	Feedback Capacitance[2] at V_{CB} = 1 V, I_E = 0, f = 1 MHz	pF		0.75	0.85
	$\|S_{21E}\|^2$	Insertion Power Gain (1) at V_{CE} = 1 V, I_C =3 mA, f = 2 GHz	dB	2.5	3.5	
	$\|S_{21E}\|^2$	Insertion Power Gain (2) at V_{CE} = 3 V, I_C =20 mA, f = 2 GHz	dB		6.5	
	NF	Noise Figure (1) at V_{CE} = 1 V, I_C = 3 mA, f = 2 GHz	dB		1.7	2.5
	NF	Noise Figure (2) at V_{CE} = 3 V, I_C = 7 mA, f = 2 GHz	dB		1.5	

Notes: 1. Pulsed measurement, pulse width ≤ 350 µs, duty cycle ≤ 2 %.
2. Collector to base capacitance when measured with capacitance meter (automatic balanced bridge method), with emitter connected to guard pin of capacitances meter.

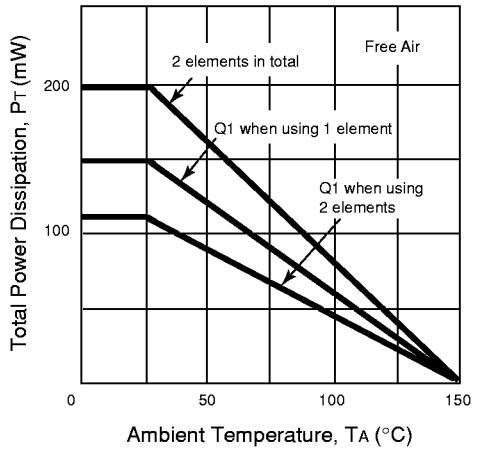
ABSOLUTE MAXIMUM RATINGS[1] (T_A = 25°C)

SYMBOLS	PARAMETERS	UNITS	RATINGS	
			Q1	Q2
V_{CBO}	Collector to Base Voltage	V	9	9
V_{CEO}	Collector to Emitter Voltage	V	6	6
V_{EBO}	Emitter to Base Voltage	V	2	2
I_C	Collector Current	mA	30	100
P_T	Total Power Dissipation	mW	150	150
			200[2]	
T_J	Junction Temperature	°C	150	150
T_{STG}	Storage Temperature	°C	-65 to +150	

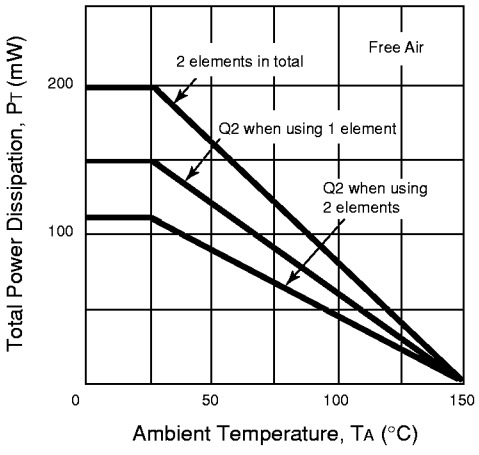
Note: 1. Operation in excess of any one of these parameters may result in permanent damage.
2. When operating both devices, the power dissipation for either device should not exceed 110 mW.

TYPICAL PERFORMANCE CURVES (T_A = 25°C)

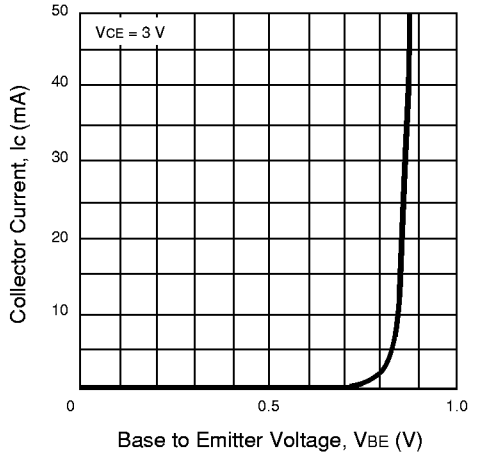
Q1
TOTAL POWER DISSIPATION vs.
AMBIENT TEMPERATURE



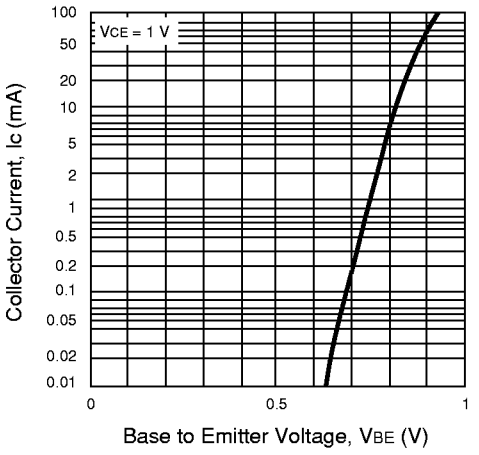
Q2
TOTAL POWER DISSIPATION vs.
AMBIENT TEMPERATURE



COLLECTOR CURRENT vs.
BASE TO EMITTER VOLTAGE



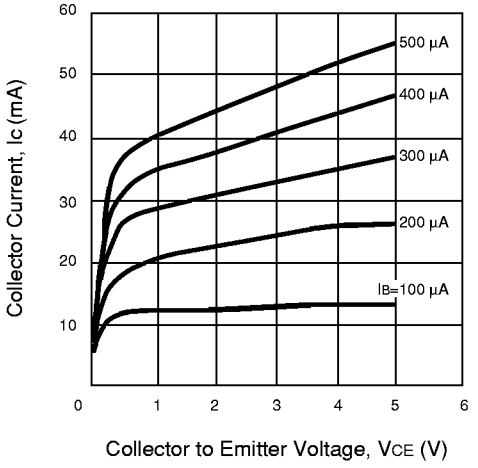
COLLECTOR CURRENT vs.
BASE TO EMITTER VOLTAGE



TYPICAL PERFORMANCE CURVES (T_A = 25°C)

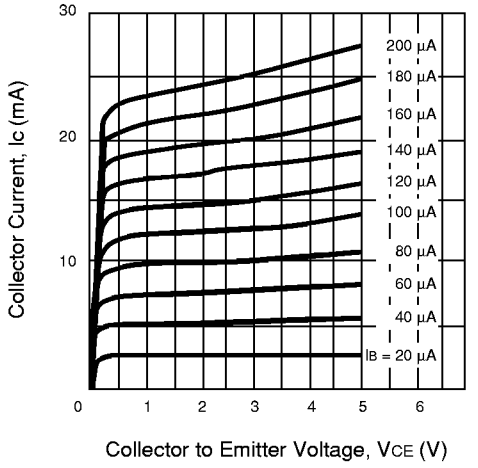
Q1

COLLECTOR CURRENT vs. COLLECTOR TO EMITTER VOLTAGE

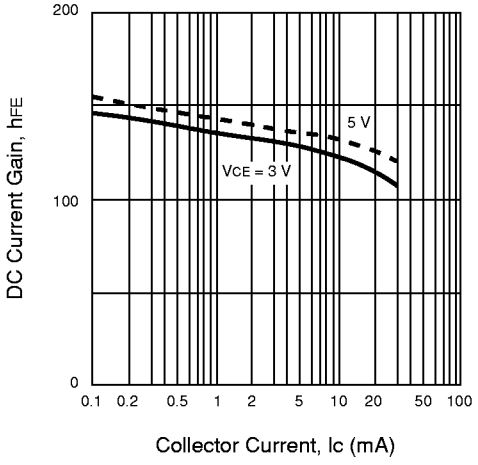


Q2

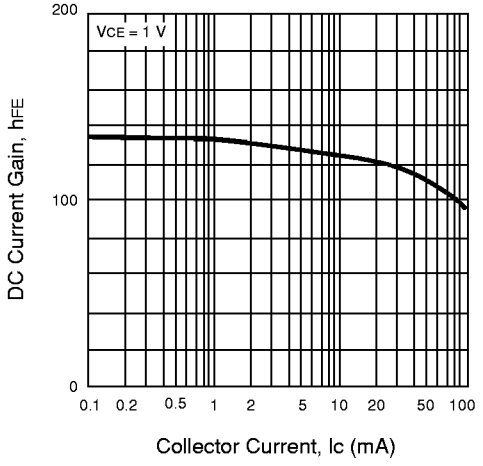
COLLECTOR CURRENT vs. COLLECTOR TO EMITTER VOLTAGE



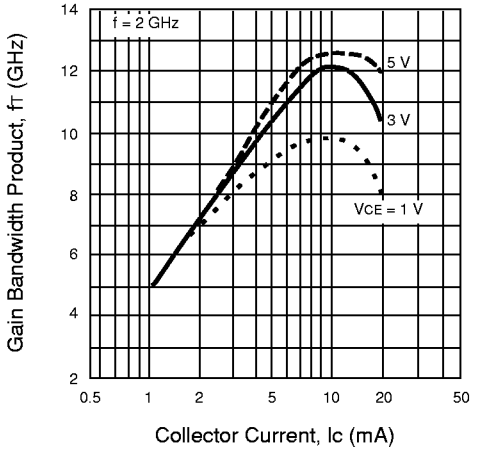
DC CURRENT GAIN vs. COLLECTOR CURRENT



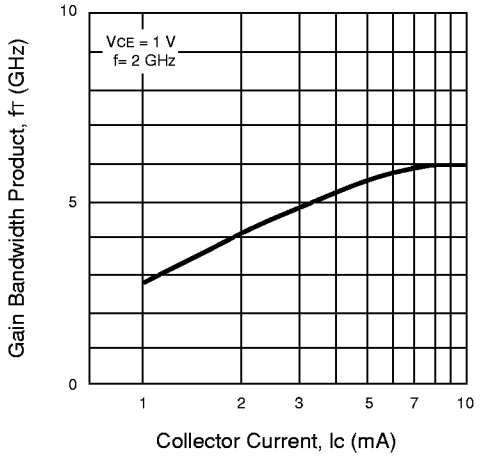
DC CURRENT GAIN vs. COLLECTOR CURRENT



GAIN BANDWIDTH PRODUCT vs. COLLECTOR CURRENT



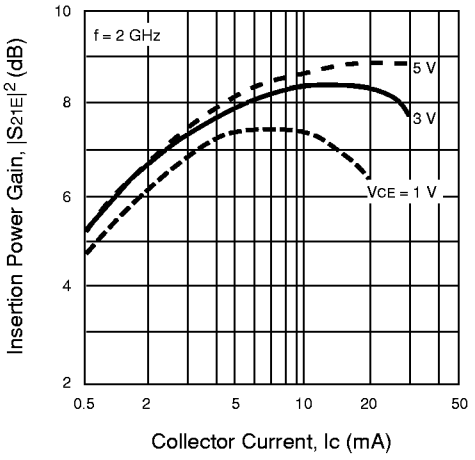
GAIN BANDWIDTH PRODUCT vs. COLLECTOR CURRENT



TYPICAL PERFORMANCE CURVES (T_A = 25°C)

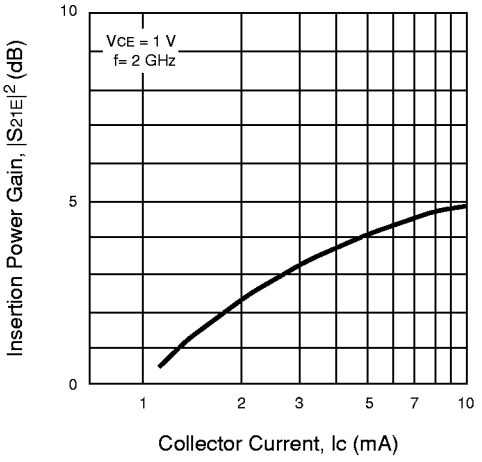
Q1

INSERTION POWER GAIN vs. COLLECTOR CURRENT



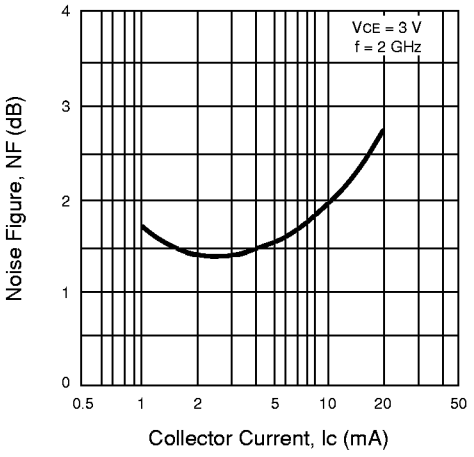
Q2

INSERTION POWER GAIN vs. COLLECTOR CURRENT



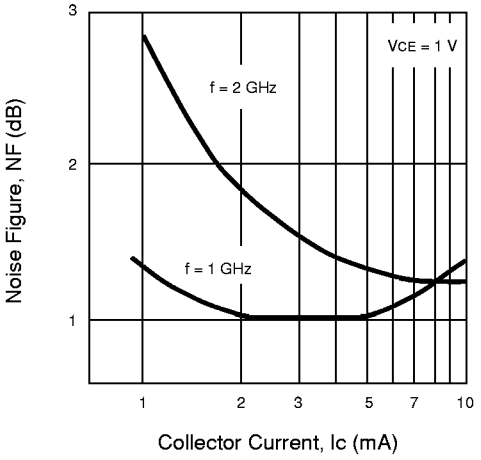
Q1

NOISE FIGURE vs. COLLECTOR CURRENT



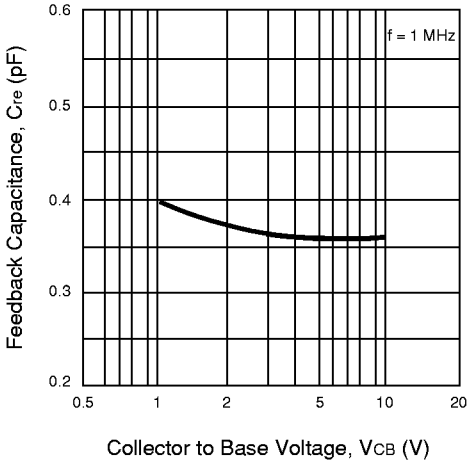
Q2

NOISE FIGURE vs. COLLECTOR CURRENT



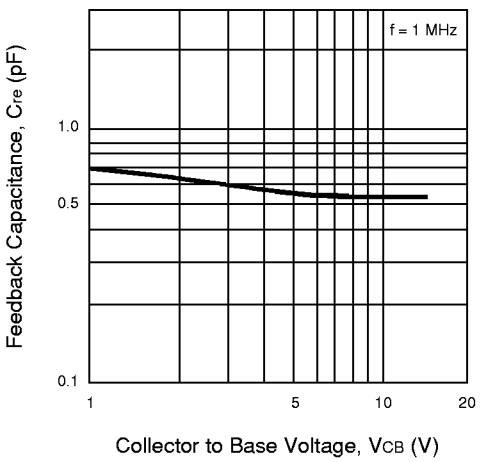
Q1

FEEDBACK CAPACITANCE vs. COLLECTOR TO BASE VOLTAGE



Q2

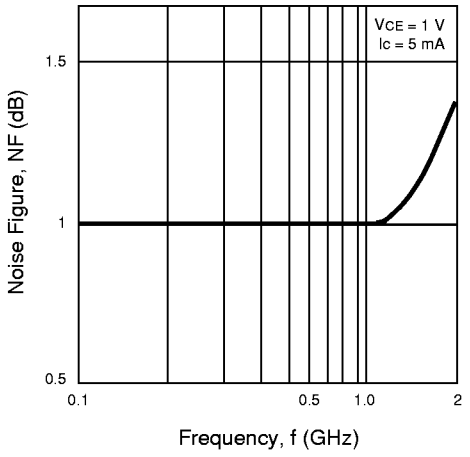
FEEDBACK CAPACITANCE vs. COLLECTOR TO BASE VOLTAGE



TYPICAL PERFORMANCE CURVES (T_A = 25°C)

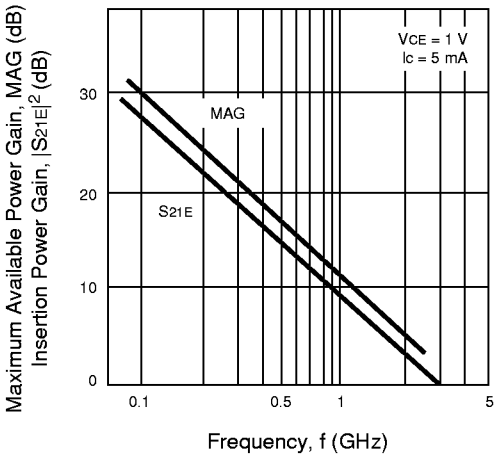
Q2

NOISE FIGURE vs. FREQUENCY



Q2

MAXIMUM AVAILABLE GAIN, INSERTION POWER GAIN vs. FREQUENCY



TYPICAL SCATTERING PARAMETERS

Q1

V_{CE} = 3 V, I_C = 1 mA, Z_0 = 50 Ω

FREQUENCY	S_{11}		S_{21}		S_{12}		S_{22}	
(GHz)	MAG	ANG	MAG	ANG	MAG	ANG	MAG	ANG
0.10	0.98	-5.93	2.38	172.32	0.02	85.76	1.00	-3.86
0.20	0.97	-11.90	2.36	165.08	0.04	81.15	0.99	-7.44
0.30	0.95	-18.17	2.39	158.35	0.06	76.27	0.97	-11.14
0.40	0.93	-24.00	2.35	151.83	0.07	72.22	0.96	-14.73
0.50	0.90	-30.10	2.35	145.70	0.09	68.30	0.94	-18.02
0.60	0.87	-36.17	2.33	140.22	0.10	64.18	0.92	-21.42
0.70	0.84	-42.49	2.30	134.45	0.12	60.68	0.89	-24.18
0.80	0.80	-48.69	2.29	129.32	0.13	56.90	0.87	-27.47
0.90	0.76	-55.28	2.29	123.53	0.14	53.94	0.84	-29.94
1.00	0.73	-61.26	2.24	118.31	0.15	51.07	0.81	-32.50
1.20	0.64	-74.79	2.19	108.30	0.16	45.85	0.76	-36.89
1.50	0.51	-96.77	2.10	93.80	0.18	39.24	0.69	-42.90
1.70	0.43	-112.09	2.00	84.74	0.19	36.24	0.65	-46.39
2.00	0.35	-138.38	1.84	72.75	0.19	32.40	0.60	-51.51
2.50	0.31	175.03	1.62	54.64	0.20	29.55	0.53	-59.91
3.00	0.35	140.64	1.41	40.02	0.21	28.96	0.47	-69.74

Q2

V_{CE} = 3 V, I_C = 1 mA, Z_0 = 50 Ω

FREQUENCY	S_{11}		S_{21}		S_{12}		S_{22}	
(GHz)	MAG	ANG	MAG	ANG	MAG	ANG	MAG	ANG
0.10	0.97	-14.32	2.42	166.29	0.04	80.18	0.99	-7.24
0.20	0.95	-28.41	2.36	154.31	0.07	70.77	0.96	-14.16
0.30	0.91	-42.45	2.34	143.61	0.10	62.19	0.91	-20.19
0.40	0.88	-55.88	2.25	133.74	0.13	54.42	0.87	-25.69
0.50	0.83	-69.17	2.21	124.69	0.14	48.08	0.81	-30.13
0.60	0.79	-81.80	2.14	116.51	0.16	42.00	0.77	-34.32
0.70	0.75	-93.67	2.06	108.52	0.17	37.41	0.72	-37.52
0.80	0.72	-104.67	1.98	101.49	0.17	33.30	0.68	-40.84
0.90	0.69	-115.37	1.91	94.57	0.18	29.92	0.65	-43.52
1.00	0.67	-124.80	1.81	88.40	0.18	27.31	0.62	-46.09
1.20	0.63	-142.25	1.66	77.30	0.18	23.77	0.57	-51.18
1.50	0.61	-163.80	1.46	63.16	0.17	22.24	0.51	-59.93
1.70	0.61	-175.60	1.35	54.92	0.16	24.02	0.48	-66.60
2.00	0.61	169.35	1.21	43.93	0.16	30.08	0.44	-78.77
2.50	0.64	149.69	1.02	28.22	0.19	41.91	0.39	-106.64
3.00	0.68	134.75	0.88	15.55	0.26	45.51	0.39	-141.18

TYPICAL SCATTERING PARAMETERS

Q1

V_{CE} = 3 V, I_C = 3 mA, Z_0 = 50 Ω

FREQUENCY	S_{11}		S_{21}		S_{12}		S_{22}	
(GHz)	MAG	ANG	MAG	ANG	MAG	ANG	MAG	ANG
0.10	0.94	-9.29	6.55	168.08	0.02	84.10	0.98	-6.91
0.20	0.90	-18.39	6.32	157.85	0.04	76.93	0.95	-13.21
0.30	0.85	-27.47	6.21	148.76	0.05	71.79	0.91	-18.80
0.40	0.80	-36.15	5.98	140.53	0.06	66.81	0.86	-23.80
0.50	0.74	-44.62	5.77	133.00	0.07	63.60	0.81	-27.41
0.60	0.67	-52.69	5.51	126.23	0.08	60.13	0.76	-31.19
0.70	0.60	-60.71	5.28	119.27	0.09	58.07	0.72	-33.67
0.80	0.54	-68.45	5.03	113.12	0.10	55.93	0.68	-36.31
0.90	0.47	-75.60	4.76	107.23	0.11	54.62	0.64	-38.10
1.00	0.42	-82.57	4.50	101.99	0.11	53.45	0.61	-39.74
1.20	0.32	-96.78	4.02	92.52	0.13	51.59	0.56	-42.63
1.50	0.21	-122.39	3.42	80.83	0.15	49.61	0.50	-46.74
1.70	0.17	-143.90	3.10	74.15	0.16	48.63	0.46	-49.50
2.00	0.16	179.12	2.70	64.83	0.18	46.70	0.42	-54.02
2.50	0.22	136.13	2.24	51.62	0.21	43.76	0.36	-63.34
3.00	0.29	115.80	1.89	39.81	0.23	40.27	0.31	-75.36

Q2

V_{CE} = 3 V, I_C = 3 mA, Z_0 = 50 Ω

FREQUENCY	S_{11}		S_{21}		S_{12}		S_{22}	
(GHz)	MAG	ANG	MAG	ANG	MAG	ANG	MAG	ANG
0.10	0.91	-20.77	6.78	160.00	0.04	76.08	0.95	-14.28
0.20	0.84	-40.45	6.30	145.15	0.06	64.72	0.86	-26.08
0.30	0.76	-59.61	5.98	132.53	0.08	56.56	0.75	-34.42
0.40	0.69	-77.35	5.54	121.70	0.10	50.58	0.66	-41.09
0.50	0.62	-93.52	5.09	112.12	0.11	47.02	0.58	-45.13
0.60	0.57	-107.23	4.61	114.36	0.12	44.57	0.51	-48.78
0.70	0.53	-119.29	4.20	97.25	0.12	43.10	0.46	-51.09
0.80	0.50	-129.99	3.84	91.32	0.13	42.46	0.42	-53.42
0.90	0.48	-139.30	3.51	85.88	0.13	41.93	0.38	-55.21
1.00	0.47	-147.65	3.25	80.98	0.14	42.00	0.36	-56.92
1.20	0.46	-161.91	2.80	72.45	0.15	42.33	0.31	-60.52
1.50	0.46	-179.07	2.33	61.22	0.17	43.12	0.25	-67.97
1.70	0.47	171.72	2.10	54.61	0.18	43.54	0.21	-74.72
2.00	0.49	160.12	1.83	45.19	0.21	44.70	0.17	-89.34
2.50	0.54	144.71	1.52	31.01	0.25	42.00	0.13	-132.57
3.00	0.59	132.90	1.29	18.97	0.30	38.08	0.17	-179.42

TYPICAL SCATTERING PARAMETERS

Q1

V_{CE} = 3 V, I_C = 5 mA, Z_0 = 50 Ω

FREQUENCY	S_{11}		S_{21}		S_{12}		S_{22}	
(GHz)	MAG	ANG	MAG	ANG	MAG	ANG	MAG	ANG
0.10	0.90	-12.12	10.05	165.07	0.02	82.08	0.97	-9.12
0.20	0.84	-23.51	9.49	152.86	0.03	74.99	0.92	-17.06
0.30	0.77	-34.84	9.08	142.06	0.05	69.42	0.85	-23.23
0.40	0.69	-45.03	8.52	132.57	0.06	65.57	0.78	-28.22
0.50	0.60	-54.58	7.94	123.96	0.07	63.02	0.72	-31.57
0.60	0.52	-62.89	7.32	116.79	0.08	60.80	0.66	-34.45
0.70	0.44	-70.48	6.74	109.99	0.08	59.78	0.62	-36.34
0.80	0.38	-77.63	6.21	104.22	0.09	58.73	0.58	-38.08
0.90	0.32	-84.12	5.71	99.08	0.10	57.98	0.55	-39.38
1.00	0.28	-90.92	5.28	94.41	0.11	57.45	0.53	-40.58
1.20	0.20	-105.44	4.56	86.53	0.12	56.41	0.48	-42.73
1.50	0.13	-137.90	3.78	76.56	0.14	54.85	0.43	-46.37
1.70	0.11	-167.88	3.39	70.79	0.15	53.69	0.40	-49.23
2.00	0.13	152.80	2.93	62.58	0.18	51.42	0.37	-54.00
2.50	0.21	121.76	2.41	50.64	0.21	47.56	0.31	-64.32
3.00	0.28	107.74	2.03	39.80	0.24	42.91	0.26	-78.22

Q2

V_{CE} = 3 V, I_C = 5 mA, Z_0 = 50 Ω

FREQUENCY	S_{11}		S_{21}		S_{12}		S_{22}	
(GHz)	MAG	ANG	MAG	ANG	MAG	ANG	MAG	ANG
0.10	0.84	-26.28	10.60	155.28	0.03	73.62	0.91	-19.87
0.20	0.75	-50.58	9.48	138.37	0.06	62.12	0.77	-34.36
0.30	0.64	-73.48	8.58	124.39	0.07	55.68	0.63	-43.20
0.40	0.56	-93.24	7.56	113.09	0.08	52.30	0.53	-49.31
0.50	0.49	-109.26	6.59	104.26	0.09	50.89	0.45	-52.83
0.60	0.45	-122.23	5.76	97.42	0.10	50.06	0.39	-55.78
0.70	0.43	-133.23	5.10	91.52	0.11	49.97	0.34	-57.54
0.80	0.41	-142.94	4.57	86.44	0.12	50.11	0.31	-59.42
0.90	0.40	-151.05	4.13	81.93	0.13	50.05	0.27	-60.94
1.00	0.40	-158.37	3.78	77.69	0.13	50.37	0.25	-62.43
1.20	0.40	-170.84	3.22	70.16	0.15	50.44	0.20	-66.17
1.50	0.41	174.38	2.64	60.16	0.18	49.56	0.15	-75.30
1.70	0.43	166.51	2.37	54.26	0.20	48.51	0.12	-85.04
2.00	0.45	156.30	2.05	45.69	0.23	46.68	0.08	-111.15
2.50	0.51	142.45	1.69	32.37	0.28	41.96	0.09	-179.51
3.00	0.56	131.71	1.44	20.88	0.32	36.35	0.17	146.82

TYPICAL SCATTERING PARAMETERS

Q1

V_{CE} = 3 V, I_C = 10 mA, Z_0 = 50 Ω

FREQUENCY	S_{11}		S_{21}		S_{12}		S_{22}	
(GHz)	MAG	ANG	MAG	ANG	MAG	ANG	MAG	ANG
0.10	0.82	-17.52	16.52	159.99	0.02	80.28	0.94	-12.68
0.20	0.72	-33.22	14.93	144.21	0.03	72.82	0.85	-22.43
0.30	0.60	-46.83	13.32	131.03	0.04	68.07	0.75	-28.43
0.40	0.49	-57.62	11.65	120.45	0.05	65.62	0.67	-32.14
0.50	0.40	-65.90	10.15	112.22	0.06	65.03	0.60	-34.25
0.60	0.33	-72.93	8.90	105.22	0.07	63.86	0.56	-35.78
0.70	0.27	-79.33	7.89	100.37	0.08	63.74	0.52	-36.80
0.80	0.22	-85.38	7.07	95.73	0.08	63.50	0.49	-37.69
0.90	0.18	-91.73	6.39	91.61	0.09	63.16	0.46	-38.46
1.00	0.15	-98.81	5.83	87.88	0.10	62.77	0.45	-39.30
1.20	0.10	-118.22	4.95	81.32	0.11	61.85	0.41	-41.01
1.50	0.07	-176.19	4.05	72.83	0.14	59.79	0.38	-44.69
1.70	0.08	149.79	3.61	67.81	0.15	58.31	0.35	-47.69
2.00	0.13	125.94	3.12	60.46	0.18	55.55	0.32	-53.15
2.50	0.21	109.57	2.54	49.58	0.22	50.37	0.27	-65.07
3.00	0.29	100.79	2.14	39.46	0.25	45.03	0.21	-81.46

Q2

V_{CE} = 3 V, I_C = 10 mA, Z_0 = 50 Ω

FREQUENCY	S_{11}		S_{21}		S_{12}		S_{22}	
(GHz)	MAG	ANG	MAG	ANG	MAG	ANG	MAG	ANG
0.10	0.70	-38.41	18.28	146.82	0.03	69.80	0.82	-29.66
0.20	0.56	-71.49	14.88	126.35	0.05	61.45	0.61	-46.31
0.30	0.45	-97.54	11.94	112.07	0.06	58.70	0.46	-54.40
0.40	0.39	-116.40	9.67	102.58	0.07	58.67	0.37	-59.06
0.50	0.35	-130.54	8.00	95.72	0.08	59.11	0.30	-61.94
0.60	0.34	-141.64	6.81	90.48	0.09	59.40	0.26	-64.34
0.70	0.33	-150.51	5.91	85.85	0.10	59.73	0.22	-65.99
0.80	0.33	-158.31	5.24	81.79	0.11	59.53	0.19	-68.05
0.90	0.33	-164.94	4.70	78.04	0.12	59.10	0.16	-70.00
1.00	0.33	-170.77	4.27	74.52	0.14	58.94	0.14	-72.05
1.20	0.34	179.29	3.60	68.08	0.16	57.53	0.11	-78.53
1.50	0.37	167.43	2.93	59.24	0.19	54.68	0.06	-101.03
1.70	0.39	160.78	2.62	53.77	0.21	52.45	0.05	-135.60
2.00	0.42	152.28	2.26	45.88	0.25	48.84	0.06	168.53
2.50	0.48	140.09	1.85	33.78	0.30	41.93	0.14	138.30
3.00	0.54	130.31	1.57	22.81	0.34	34.93	0.22	124.44

TYPICAL SCATTERING PARAMETERS

Q2

V_{CE} = 3 V, I_C = 7 mA, Z_0 = 50 Ω

FREQUENCY	S_{11}		S_{21}		S_{12}		S_{22}	
(GHz)	MAG	ANG	MAG	ANG	MAG	ANG	MAG	ANG
0.10	0.78	-31.29	13.97	151.51	0.03	71.78	0.87	-24.42
0.20	0.66	-59.66	12.04	132.90	0.05	60.97	0.70	-40.28
0.30	0.54	-84.82	10.35	118.21	0.07	56.44	0.55	-48.33
0.40	0.47	-104.53	8.72	107.56	0.08	55.05	0.45	-54.30
0.50	0.42	-119.83	7.38	99.69	0.09	54.45	0.37	-57.44
0.60	0.39	-132.03	6.34	93.65	0.10	54.56	0.32	-60.00
0.70	0.37	-142.05	5.56	88.39	0.11	54.88	0.28	-61.66
0.80	0.36	-150.83	4.94	83.86	0.11	55.01	0.24	-63.45
0.90	0.36	-158.17	4.45	79.83	0.12	55.07	0.21	-65.04
1.00	0.36	-164.78	4.05	75.94	0.13	55.03	0.19	-66.66
1.20	0.37	-175.89	3.43	69.04	0.15	54.31	0.15	-71.21
1.50	0.39	170.80	2.80	59.72	0.19	52.52	0.10	-83.83
1.70	0.40	163.55	2.51	54.06	0.21	50.73	0.07	-100.27
2.00	0.43	154.21	2.17	45.65	0.24	47.90	0.05	-148.70
2.50	0.49	141.28	1.78	33.14	0.29	41.96	0.11	152.83
3.00	0.55	131.03	1.51	21.87	0.33	35.50	0.19	132.79

Q2

V_{CE} = 3 V, I_C = 20 mA, Z_0 = 50 Ω

FREQUENCY	S_{11}		S_{21}		S_{12}		S_{22}	
(GHz)	MAG	ANG	MAG	ANG	MAG	ANG	MAG	ANG
0.10	0.51	-57.90	27.75	136.02	0.02	69.14	0.70	-39.87
0.20	0.37	-97.17	19.04	114.46	0.04	64.83	0.46	-56.12
0.30	0.31	-120.97	13.81	103.21	0.05	65.82	0.33	-62.80
0.40	0.29	-137.00	10.72	95.92	0.06	66.30	0.26	-66.88
0.50	0.28	-148.56	8.73	90.60	0.08	66.42	0.21	-69.42
0.60	0.28	-157.11	7.34	86.37	0.09	66.46	0.17	-72.27
0.70	0.28	-164.14	6.36	82.37	0.10	66.07	0.14	-74.72
0.80	0.29	-170.13	5.60	78.94	0.11	65.59	0.12	-78.14
0.90	0.29	-175.24	5.00	75.67	0.13	64.35	0.10	-82.37
1.00	0.30	-179.80	4.54	72.57	0.14	63.61	0.08	-87.43
1.20	0.32	172.24	3.81	66.74	0.16	61.26	0.05	-106.92
1.50	0.34	162.54	3.09	58.59	0.20	57.09	0.04	-169.73
1.70	0.37	156.95	2.75	53.51	0.22	54.21	0.06	160.94
2.00	0.40	149.52	2.37	46.16	0.26	46.16	0.11	140.92
2.50	0.46	138.42	1.94	34.42	0.31	34.42	0.19	127.04
3.00	0.52	129.12	1.63	23.88	0.35	23.88	0.27	117.03

NONLINEAR MODEL

BJT NONLINEAR MODEL PARAMETERS(1)

Parameters	Q1	Q2	Parameters	Q1	Q2
IS	7e-16	3.8e-16	MJC	0.34	0.48
BF	109	135.7	XCJC	0	0.56
NF	1	1	CJS	0	0
VAF	15	28	VJS	0.75	0.75
IKF	0.19	0.6	MJS	0	0
ISE	7.9e-13	3.8e-15	FC	0.5	0.75
NE	2.19	1.49	TF	2e-12	11e-12
BR	1	12.3	XTF	5.2	0.36
NR	1.08	1.1	VTF	4.58	0.65
VAR	12.4	3.5	ITF	0.01	0.61
IKR	Infinity	0.06	PTF	0	50
ISC	0	3.5e-16	TR	1e-9	32e-12
NC	2	1.62	EG	1.11	1.11
RE	1.3	0.4	XTB	0	0
RB	10	6.14	XTI	3	3
RBM	8.34	3.5	KF	0	1.5e-14
IRB	0.009	0.001	AF	1	1.22
RC	10	4.2			
CJE	0.4e-12	0.796e-12			
VJE	0.81	0.71			
MJE	0.5	0.38			
CJC	0.18e-12	0.549e-12			
VJC	0.75	0.65			

(1) Gummel-Poon Model

UNITS

Parameter	Units
time	seconds
capacitance	farads
inductance	henries
resistance	ohms
voltage	volts
current	amps

MODEL RANGE

Frequency: 0.1 to 3.0 GHz

Bias: V_{CE} =0.5 V to 5 V, I_C = 1 mA to 10 mA

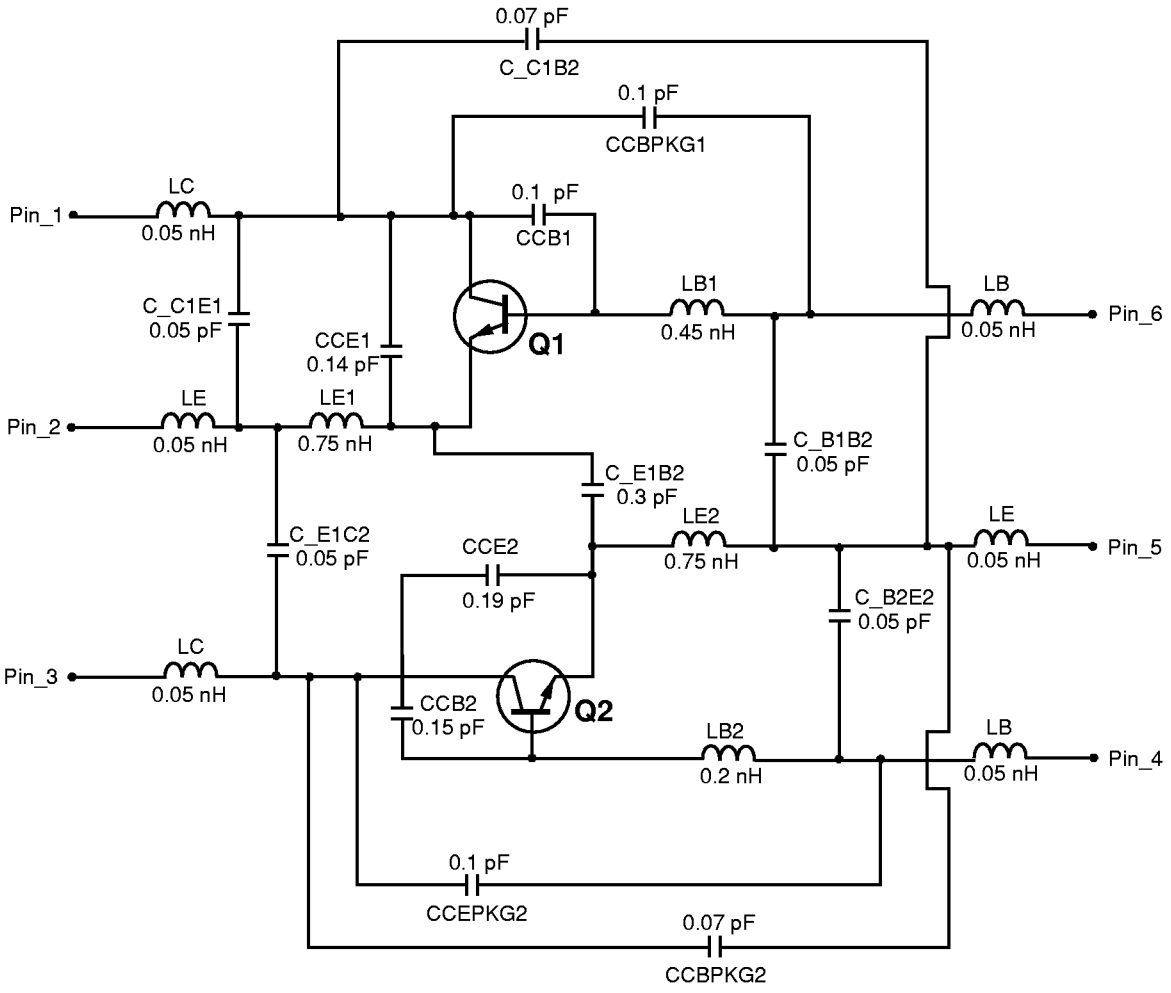
Date: 10/98

Note:

This nonlinear model utilized the latest data available. See our Design Parameter Library at **www.cel.com** for this data.

NONLINEAR MODEL

SCHEMATIC



MODEL RANGE

Frequency: 0.1 to 3.0 GHz

Bias: V_{CE} = 0.5 V to 5 V, I_C = 1 mA to 10 mA

Date: 10/98

BUILT-IN TRANSISTORS

	Q1	Q2
3-pin small mini mold part No.	NE68530	NE68830

The UPA833TF features the Q1 and Q2 in inverted positions.

ORDERING INFORMATION

PART NUMBER	QUANTITY	PACKAGING
UPA836TF-T1	3000	Tape & Reel